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# Visible-light driven water splitting over BiFeO<sub>3</sub> photoanodes grown *via* the LPCVD reaction of [Bi(O<sup>t</sup>Bu)<sub>3</sub>] and [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> and enhanced with a surface nickel oxygen evolution catalyst†

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Phase-pure BiFeO<sub>3</sub> films were grown directly *via* dual-source low-pressure CVD (LPCVD) from the ligand-matched precursors [Bi(O<sup>t</sup>Bu)<sub>3</sub>] and [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub>, without the requirement for oxidising gas or post deposition annealing. Photocatalytic testing for water oxidation revealed extremely high activity for PEC water splitting and photocatalytic water oxidation under visible light irradiation ( $\lambda > 420$  nm) with a benchmark IPCE for BiFeO<sub>3</sub> of 23% at 400 nm. The high activity is ascribed to the ultrafine morphology achieved *via* the LPCVD process. The performance was enhanced by over four times when the BiFeO<sub>3</sub> photoanode is coupled to a Ni–B surface OEC.

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## Introduction

Solar generation of fuels using wide spectrum responsive photocatalysts is a potential solution to meet the rapid increase in energy demands of a growing global population.<sup>1,2</sup> The most commonly used materials for photocatalytic water splitting are transition metal oxides but the band-gaps of these materials (over 3.0 eV) are too high to serve as efficient photocatalysts under visible light irradiation.<sup>3</sup> A number of steps have been taken to reduce their band-gap and increase their visible response, mainly through doping (*e.g.* with nitrogen, sulfur) or through coupling with visible light responsive molecular catalysts or dyes. The search for efficient, stable, low cost photocatalysts for the kinetically slow four electron process of water oxidation is regarded to be a significant hurdle for the introduction of large-scale water splitting devices.<sup>4</sup> Recombination of electron-hole pairs is an additional limiting factor over efficiency; however a viable solution is the use of a photoelectrochemical (PEC) cell, where an

external voltage can efficiently separate photo-generated charge carriers to drive electron migration toward the conducting back-contact to reach the counter-electrode *via* an external wire, where proton reduction to hydrogen gas may occur. In addition, the loading of co-catalysts that can act as either electron or hole acceptors for improved charge separation is a promising strategy, leading to the adaptation of a junction architecture.<sup>5</sup>

Perovskite bismuth ferrite (BiFeO<sub>3</sub>, “BFO”) exhibits a direct band-gap of approximately 2.2 eV and is a promising multifunctional material that also exhibits simultaneous ferroelectric and ferromagnetic ordering in addition to photovoltaic<sup>6</sup> and photocatalytic properties;<sup>7–9</sup> Indeed, the recent successful application of inorganic and hybrid perovskite structured materials such as BiFeO<sub>3</sub>, CsSnI<sub>3</sub>, and CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> for solar energy conversion emphasises that polar semiconductors can be used in conventional photovoltaic architectures and has led to renewed interest in these “photoferroic” materials.<sup>10</sup> BiFeO<sub>3</sub> has been demonstrated to be a promising oxygen evolution photocatalyst exhibiting high efficiencies under both UV- and visible light irradiation,<sup>11,12</sup> and recently, we have demonstrated the material to be an excellent wide spectrum photocatalyst for water oxidation, showing that the material has sufficient overpotential for water oxidation in the absence of an electrical or chemical bias.<sup>13</sup> A further advantage of BiFeO<sub>3</sub> is that its spontaneous polarization in the ferroelectric domains leads to band bending, that transports photo-generated electrons and holes in opposite directions, resulting in spatially resolved reactivity and improved charge separation.<sup>14</sup>

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A major hurdle for water splitting devices is the difficulty in scale up of production, which typically requires high surface area catalysts to be grown uniformly under relatively mild conditions to be cost effective.<sup>15</sup> Thin film growth *via* Chemical Vapour Deposition (CVD) has many potential advantages including excellent substrate coverage, low-cost, ease of scale-up, control over thickness and morphology and high throughput capabilities. However, growth of stoichiometrically pure BiFeO<sub>3</sub> films using chemical deposition techniques is challenging due to the prevalence of parasitic co-phases and evaporation of bismuth at elevated temperatures;<sup>16–18</sup> and in all previous examples the use of oxidising gases or post-growth heat treatment have been required for fully oxygenated films.<sup>19</sup> Typical bismuth precursors for CVD also suffer from drawbacks such as poor volatilities {[BiI<sub>3</sub>],<sup>20</sup> [Bi(C<sub>6</sub>H<sub>5</sub>)<sub>3</sub>],<sup>21</sup> [Bi(O<sub>2</sub>CNPr<sup>i</sup>)<sub>2</sub>],<sup>22</sup> decomposition characteristics {[Bi(thd)<sub>3</sub>],<sup>23</sup> or sensitivity to air and moisture – {[Bi(mmp)<sub>3</sub>],<sup>24</sup> [Bi(CH<sub>3</sub>)<sub>3</sub>],<sup>25</sup> which makes the growth of pure BiFeO<sub>3</sub> particularly challenging.

Here, we report the growth of phase-pure BiFeO<sub>3</sub> films *via* a dual-source LPCVD reaction utilizing volatile [Bi(O<sup>t</sup>Bu)<sub>3</sub>] and [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> precursors. The use of these ligand-matched precursors decreases the likelihood of unwanted side-reactions occurring in the gas-phase and also eliminates the need for an oxidizing gas during deposition or a post-growth annealing step. The effect of substrate temperature and system pressure on composition and phase was also investigated. Films were fully characterized and surprisingly, were found to be highly active photocatalysts for water oxidation under both full arc and visible light irradiation showing excellent stability and respectable efficiency. A nickel surface OEC further improves the water splitting capability by increasing charge separation efficiency and improving kinetics for the process, resulting in stable H<sub>2</sub> and O<sub>2</sub> evolution under an applied bias.

## Experimental

### Precursor synthesis

Standard Schlenk line procedures were used. Bismuth(III) *tert*-butoxide, [Bi(O<sup>t</sup>Bu)<sub>3</sub>], was synthesised according to the literature *via* the metathesis reaction of BiCl<sub>3</sub> and three molar equivalents of NaO<sup>t</sup>Bu.<sup>26</sup> Iron(III) *tert*-butoxide, [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub>, synthesised using a modified literature preparation *via* the metathesis reaction between anhydrous FeCl<sub>3</sub> and three molar equivalents of NaO<sup>t</sup>Bu, was obtained as dark green crystals *via* sublimation under reduced pressure (10<sup>−1</sup> mbar, 120 °C).<sup>27</sup> Both products were stored in a nitrogen filled MBraun Unilab glovebox. TGA studies were conducted using a Netzsch 449 C Instrument under a flow of helium gas (50 sccm) with a heating rate of 10 °C min<sup>−1</sup>. TGA samples were sealed in a glovebox into aluminium pans and pierced with a hole in the lid prior to analysis. Vapour pressure measurement for [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> was obtained from SAFC Ltd. The decomposition characteristics of [Bi(O<sup>t</sup>Bu)<sub>3</sub>] and [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> were analysed *via* TGA and their vapour pressures were plotted to identify suitable evaporation conditions (Fig. S1, ESI†).

### Film growth

A schematic diagram of the LPCVD apparatus is shown in Scheme 1 in the ESI.† A base pressure of 2 × 10<sup>−3</sup> mbar was achieved before use, to ensure as far as possible that no air and moisture remained in the system. The total reactor pressure was varied *via* the use of a mechanical throttle valve. Each deposition was carried out for 1 hour. Films were deposited on borosilicate glass microscope slides (3 cm × 2 cm), FTO-coated glass and platinised silicon wafers. For deposition of BiFeO<sub>3</sub> films, a 2 : 1 molar ratio of Bi : Fe precursor was utilised {[Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> exists as a dimer}. By information obtained from the vapour pressure and TGA curves, 230 mg (0.54 mmol) of [Bi(O<sup>t</sup>Bu)<sub>3</sub>] was used for each deposition and evaporated at 110 °C (*V*<sub>p</sub> = 1.1 mmHg). 150 mg of [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> (0.27 mmol) was evaporated at 100 °C (*V*<sub>p</sub> = 2.4 mmHg). Nitrogen (BOC, 99.96%, 50 sccm) was used as the carrier gas for each precursor with a plain line flow of nitrogen (50 sccm). Photo-assisted electrodeposition of Nickel-borate (Ni-B) was carried out in a solution of 1 mM nickel(II) nitrate in 0.1 M aqueous potassium borate, using an applied bias of 0.5 V for a period of 15 minutes under 100 mW cm<sup>−2</sup> irradiation, then rinsed with de-ionised water and dried at room temperature. A current density of 25 μA cm<sup>−2</sup> was observed during the deposition.

### Film analysis

X-ray diffraction was carried out using a Bruker-AXS D4 powder diffractometer in reflection geometry using Cu-K<sub>α</sub> radiation ( $\lambda$  = 1.54056 Å) on a rotating sample holder in the range 10–70° 2 $\theta$ , 0.05° step size, with 2 s per step. Phase information was obtained from the Diffracplus EVA program suite (version 2) and ICSD. Scanning electron microscopy (SEM) was used in order to examine surface morphology and film thickness. Images were obtained on a Jeol JSM-6301F Field Emission Microscope at 5 kV, after coating samples with an ultrathin layer of gold to prevent charging. Quantitative analyses of bismuth and iron were carried out *via* WDX using a Philips XL30ESEM Machine operating at 10 kV, equipped with an Oxford Instruments INCA detector. Films were carbon coated prior to analysis to prevent charging. XPS analysis was performed using a Kratos AXIS Ultra machine with a delay line detector under a pressure of 10<sup>−9</sup> torr. A monochromated Al-K<sub>α</sub> X-ray source producing a full width at half maximum (FWHM) on the Ag 3d<sub>5/2</sub> peak of 0.48 eV was used. Raman spectra were acquired using a Renishaw Raman 1000 System using a helium-neon laser wavelength of 514.5 nm at liquid nitrogen temperature (−195 °C) using a cold stage and temperature controller equipped with a cryo pump. AFM analysis was performed using a Veeco Dimension 3100 machine in intermittent contact mode. UV-Vis spectra were recorded in transmission mode over the range 300–2500 nm using a Perkin Elmer Lambda 950 photospectrometer. Magnetism measurements (*M*–*H* hysteresis and ZFC-FC magnetisation) were conducted using a Quantum Design SQUID Vibrating Sample Magnetometer (VSM) with a maximum field setting of 7 T (70 000 Oe). Films were mounted on a 4 mm diameter



quartz rod using a vinyl phenolic adhesive (code GE7031, stable up to 400 K) and suspended parallel to the magnetic field (in-plane). The magnetic moment was corrected by subtracting the diamagnetic contribution from the uncoated substrate.

### Photocatalytic testing

**Photocatalytic oxygen evolution.** Selected films were used to photo-oxidise water using sacrificial reagents (alkaline sodium persulphate) under UVA (365 nm) and simulated solar irradiation (150 W Xe lamp), the details of which have been reported elsewhere.<sup>28</sup> In a typical experiment, the film was immersed in 30 cm<sup>3</sup> aqueous solution under strong stirring conditions (55 rpm) in a quartz vessel with water-cooled jacket ( $T = 298$  K). The photo-oxidation of water is biased through immersion in a solution containing a sacrificial electron-acceptor (scavenger) composed of 0.01 M Na<sub>2</sub>S<sub>2</sub>O<sub>8</sub> in 0.1 M NaOH (pH 11).<sup>29</sup> The MPD is comprised of a circular shaped silver electrode (counter and reference) and a platinum electrode disc (cathode) connected *via* a salt bridge (3 M KCl).<sup>29</sup> The Pt electrode is protected from the test solution by a gas-permeable PTFE membrane.<sup>13</sup> The size of the film was 2.5 cm<sup>2</sup>.

**Photoelectrochemical testing.** These were carried out using an Iviumstat potentiostat and associated Ivium software. A three electrode setup was utilized within a sealed borosilicate glass cell with quartz windows (Adams and Schittenden Co., USA). A Pt wire mesh and Ag/AgCl electrode were used as the counter and reference electrodes, respectively. An aqueous solution of 0.2 M Na<sub>2</sub>SO<sub>4</sub> was used as the electrolyte (pH 6.5) and was purged with argon gas for 15 min to remove dissolved oxygen. The potential was converted to RHE (reference hydrogen electrode) potentials using the Nernst equation:

$$E(\text{RHE}) = E(\text{Ag}/\text{AgCl}) + (0.059 \times \text{pH}) + 0.197 \text{ V}$$

The light source was a 150 W Xenon lamp (Newport, USA) equipped with a standard AM 1.5 G filter; the light intensity was calibrated to 1 sun (100 mW cm<sup>-2</sup>), measured using a silicon photodiode and Newport hand-held Optical Meter (Model 1918-R). Visible light experiments were conducted using a long-pass filter ( $\lambda > 420$  nm, Newport). The scan rate was 10 mV s<sup>-1</sup>, a mechanical chopper was used to chop the light and the scanned range was 0 to +1.5 V (vs. Ag/AgCl). The

illuminated area was 0.5 cm × 0.5 cm. Faradaic efficiency (gas evolution) measurements were carried out using a gas-tight custom-made reactor PEC cell (Adams and Schittenden Co., USA) which was thoroughly purged with argon for 1 hour prior to irradiation. The solution was stirred vigorously (1000 rpm) during testing to ensure as much dissolved oxygen as possible is transferred to the headspace. Gas concentration analysis was performed using a GC (Varian 430-GC, TCD, 5 Å molecular sieve column, argon carrier gas 99.999%) by taking 250 µl samples of the gas in the headspace of the PEC reactor at regular intervals. An external bias of 1.2 V vs. RHE was used.

Incident photon to current conversion efficiency (IPCE) was measured with the aid of a monochromator, and calculated using the following equation:<sup>30</sup>

$$\text{IPCE (\%)} = \frac{[1240 \times \text{Photocurrent density}]}{[\text{Wavelength} \times \text{photon flux}] \times 100\%}$$

## Results and discussion

The LPCVD reaction of [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> and [Bi(O<sup>t</sup>Bu)<sub>3</sub>] resulted in adherent films at a temperatures between 475 and 550 °C. All films displayed good coverage, were red-orange in colour and could not be removed *via* tissue or scotch tape, but were scratched with a steel stylus. The deposition conditions are summarised in Table 1.

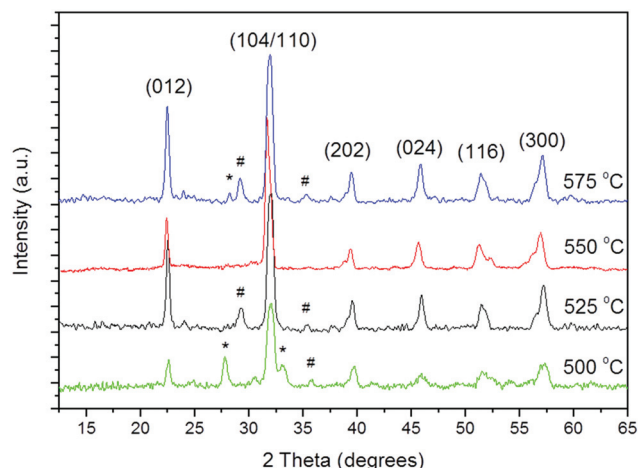
BiFeO<sub>3</sub> was only detected above 500 °C (Fig. 1) with films deposited below this temperature comprised of Bi<sub>2</sub>Fe<sub>4</sub>O<sub>9</sub> and Bi<sub>25</sub>FeO<sub>40</sub>/Bi<sub>24</sub>Fe<sub>2</sub>O<sub>39</sub> from XRD analysis (ESI Fig. S2†); surprisingly WDX measurements showed the low temperature films to be compositionally rich in iron rather than bismuth, with bismuth incorporation increasing as a function of deposition temperature. At 550 °C there were virtually no impurity phases observed (Fig. 1) and a near 1 : 1 Bi : Fe ratio was observed as expected for BiFeO<sub>3</sub>. Hexagonal unit cell parameters of  $a = b = 5.58$  (2) Å,  $c = 13.90$  (1) Å, ( $\alpha = \beta = 90^\circ$ ,  $\gamma = 120^\circ$ , space group  $R3c$ ) were obtained *via* unit cell refinement and are in agreement with literature values for bulk rhombohedral BiFeO<sub>3</sub> ( $a = b = 5.57414$  (4) Å,  $c = 13.85882$  (6) Å, JCPDS = 71-2494);<sup>31</sup> a relatively small shift in 2 theta value was noticed (less than 1°) but is likely due to experimental error. Film growth rates as function of temperature are shown in Table 1 and plotted as a function of temperature in the ESI, Fig. S3.† The activation energy

**Table 1** Deposition conditions for fabrication of BiFeO<sub>3</sub> thin films *via* the LPCVD reaction of [Bi(O<sup>t</sup>Bu)<sub>3</sub>] and [Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub> without oxidising gas

Substrate temp/°C	Reactor pressure/mbar	Phase(s) obtained <i>via</i> XRD	Thickness/nm	Deposition rate/nm min <sup>-1</sup>	Band-gap/eV	At. % Bi : Fe (from WDX)
475	8	Bi <sub>2</sub> Fe <sub>4</sub> O <sub>9</sub> + Bi <sub>25</sub> FeO <sub>40</sub>	470	8	—	16 : 84
500	8	BiFeO <sub>3</sub> + Bi <sub>2</sub> Fe <sub>4</sub> O <sub>9</sub> + Bi <sub>25</sub> FeO <sub>40</sub>	600	10	2.2	34 : 66
525	8	BiFeO <sub>3</sub> + Bi <sub>25</sub> FeO <sub>40</sub>	640	11	2.3	39 : 61
550	8	BiFeO <sub>3</sub>	880	15	2.4	48 : 52
575	8	BiFeO <sub>3</sub> + Bi <sub>25</sub> FeO <sub>40</sub>	210	4	2.2	45 : 54
550	15	BiFeO <sub>3</sub> + Bi <sub>2</sub> Fe <sub>4</sub> O <sub>9</sub>	940	16	2.2	55 : 45
550	30	BiFeO <sub>3</sub> + Bi <sub>2</sub> Fe <sub>4</sub> O <sub>9</sub>	1200	20	2.4	59 : 41
550	45	BiFeO <sub>3</sub> + Bi <sub>2</sub> Fe <sub>4</sub> O <sub>9</sub>	1450	24	2.3	37 : 63







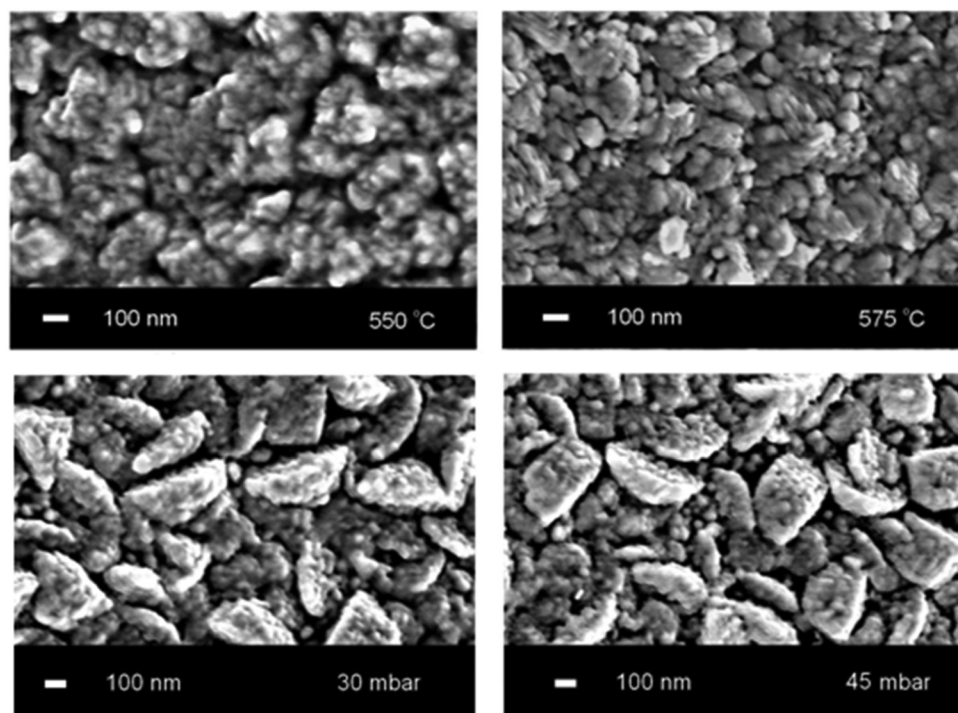
**Fig. 1** X-ray diffraction patterns of the BiFeO<sub>3</sub> films deposited at 500, 525, 550 and 575 °C at 8 mbar pressure. Peaks marked with # and \* correspond to Bi<sub>25</sub>FeO<sub>40</sub> and Bi<sub>2</sub>Fe<sub>4</sub>O<sub>9</sub> phases respectively.

for the process was calculated to be approximately 360 kJ mol<sup>-1</sup> (*ca.* 90 kcal mol<sup>-1</sup>). Increasing the total system pressure whilst maintaining a growth temperature of 550 °C led to formation of Bi<sub>2</sub>Fe<sub>4</sub>O<sub>9</sub> impurity and iron rich films (ESI Fig. S4†), likely due to the complex kinetics of the Fe<sub>2</sub>O<sub>3</sub>–Bi<sub>2</sub>O<sub>3</sub> system which can easily lead to co-existence of Bi<sub>2</sub>Fe<sub>4</sub>O<sub>9</sub> and BiFeO<sub>3</sub>. Bi<sub>2</sub>Fe<sub>4</sub>O<sub>9</sub> is a kinetically stable phase<sup>32–35</sup> and the activation energies for formation of BiFeO<sub>3</sub> and Bi<sub>2</sub>Fe<sub>4</sub>O<sub>9</sub> are very similar

(96.6 ± 9 kcal mol<sup>-1</sup> and 99.4 ± 9 kcal mol<sup>-1</sup>, respectively),<sup>36</sup> contributing to the difficulties in growing phase-pure BiFeO<sub>3</sub>. A dramatic increase in film thickness was also observed at increased deposition pressure (Table 1).

The morphologies of the films were investigated using SEM (Fig. 2), showing films with dense and uniform packing of the particles, particularly at 575 °C where films appeared flatter with fewer voids but more coalescence between particles. Individual particles were estimated to be 50 nm in diameter. Upon increasing the substrate temperature the morphology appeared more uniform and dense, whereas increasing the system pressure appeared to have little effect upon the morphology of BiFeO<sub>3</sub>. Estimation of the average particle size using the Scherrer equation gave particle diameters of 35 nm and 65 nm for films deposited at 15 mbar and 30 mbar, suggesting that the increase in deposition rate results in larger particle sizes. At 30 mbar, distinct crescent-shaped structures were apparent, in contrast to those obtained at 8 mbar, where films were composed of globular particles approximately 50 nm in diameter.

AFM analysis of the BiFeO<sub>3</sub> film deposited at 550 °C, 8 mbar (Fig. 3) showed globular and spherical particles of approximately 50 nm diameter clustered together to form larger aggregates. Although the globular morphology is similar to that observed in the top-down SEM images, the morphology appears much rougher with more features. The coverage nevertheless is continuous over the substrate and there are no voids. The root mean square (rms) roughness of the sample was calculated at 60 nm which is high for typical LPCVD films, but is similar to the value obtained for AACVD-grown BiFeO<sub>3</sub> films



**Fig. 2** Top-down SEM images of BiFeO<sub>3</sub> films deposited at 550 and 575 °C, and at 30 and 45 mbar (550 °C).



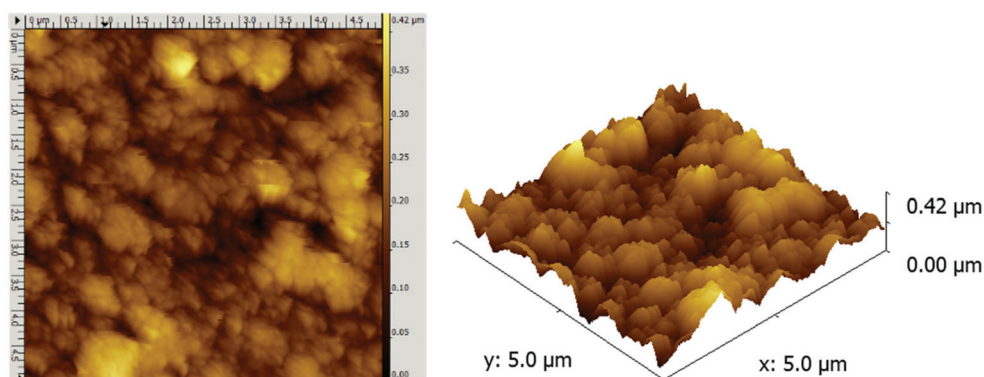


Fig. 3 A 5  $\mu\text{m}$  field size (left) and the corresponding 3D AFM image of the  $\text{BiFeO}_3$  film formed *via* LPCVD of  $[\text{Bi}(\text{O}^t\text{Bu})_3]$  and  $[\text{Fe}(\text{O}^t\text{Bu})_3]_2$  at 550  $^\circ\text{C}$ , 8 mbar.

reported recently (62 nm).<sup>13</sup> This high surface roughness (area) is likely to be beneficial for surface area applications such as photocatalysis.

Low temperature Raman spectroscopy was used to verify phase purity of a  $\text{BiFeO}_3$  films deposited at 550  $^\circ\text{C}$ , 8 mbar (Fig. 4). For single crystal  $\text{BiFeO}_3$ , one would expect to observe a total of 13 peaks in the Raman spectrum due to the  $4A_1$  and  $9E$  phonon modes.<sup>37</sup> Peaks assigned to the  $A_1$  phonon mode were observed at 147, 175, 223 and 410  $\text{cm}^{-1}$ , whilst peaks assigned to the  $E$  phonon mode were observed at 134, 265, 280, 351, 374, 473 and 526  $\text{cm}^{-1}$  and is consistent with those reported in the literature.<sup>38,39</sup> Encouragingly, peaks for  $\text{Bi}_x\text{Fe}_y\text{O}_z$  or  $\text{FeO}_x$  impurity phases were not observed in our spectra.

The chemical environment of a  $\text{BiFeO}_3$  film deposited at 550  $^\circ\text{C}$  (8 mbar) was analysed *via* XPS. The Fe 2p core level (Fig. 5) is split with the Fe  $2p_{1/2}$  peak at 724.8 eV and a broad asymmetric Fe  $2p_{3/2}$  peak at 711 eV revealing the predominant presence of iron in the +3 oxidation state, and typical of iron in  $\text{BiFeO}_3$  species. As reported in the literature<sup>18</sup> the  $\text{Fe}^{3+}$  satellite peak is usually broad and here it was observed at 717 eV as

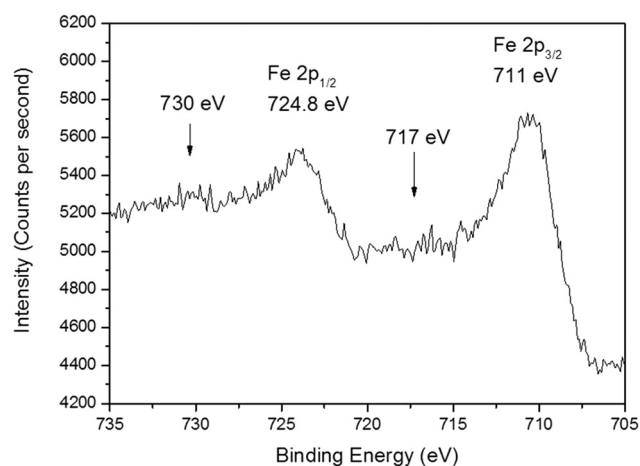


Fig. 5 High resolution XPS spectrum of the iron 2p region.

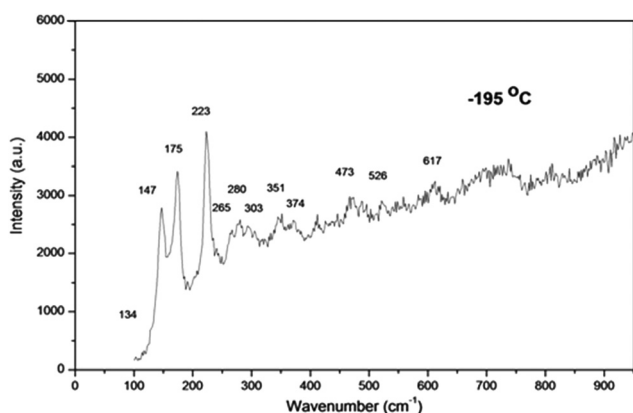


Fig. 4 Raman spectra of a  $\text{BiFeO}_3$  film deposited at 550  $^\circ\text{C}$ , 8 mbar, recorded at  $-195\text{ }^\circ\text{C}$ .

a broad shoulder to the main Fe  $2p_{3/2}$  peak, characteristic of the presence of pure  $\text{Fe}^{3+}$  in a sample. The spectra is largely flat in this region so it is difficult to assign satellites with any certainty. Furthermore, it is unlikely that the Fe ionisation originates from impurity  $\text{Fe}_3\text{O}_4$  species as an additional broad shoulder (at 707 eV) to the peak at 711 eV is expected.<sup>40</sup> Our spectrum is almost identical to that reported in the seminal text by Eerenstein *et al.* for  $\text{BiFeO}_3$  films grown *via* PLD.<sup>41</sup> In addition, the smaller peak at 730 eV corresponds to the second Fe  $2p_{1/2}$  satellite peak, in agreement with XPS spectra of pure  $\text{Fe}^{3+}$  in  $\alpha\text{-Fe}_2\text{O}_3$ ,<sup>42</sup> therefore a mixed valence state of  $\text{Fe}^{2+}$  and  $\text{Fe}^{3+}$  is unlikely in these films.

XPS analysis of the bismuth 4f region showed two distinct peaks; the  $\text{Bi}4f_{7/2}$  peak at 159.3 eV and the  $\text{Bi}4f_{5/2}$  peak at 164.6 eV (ESI Fig. S5†). Both these peaks and their positions are characteristic of the presence of bismuth in the +3 oxidation state.<sup>43</sup> XPS of the oxygen 1s region (ESI Fig. S6†) revealed two broad, asymmetric peaks at 532.4 eV (surface OH) and 529.7 eV (metal oxide). For ferroelectric characterisation,  $\text{BiFeO}_3$  films were grown directly on to 1  $\text{cm}^2$  Pt/Si wafers. The



room temperature P-E loop measured at 1 kHz (ESI Fig. S7†) revealed a remnant polarisation of  $2.4 \mu\text{C cm}^{-2}$  and saturated polarisation of  $3.9 \mu\text{C cm}^{-2}$  with coercivity of  $45 \text{ kV cm}^{-1}$ . The remnant polarisation is much higher than those reported by Tasaki *et al.*<sup>44</sup> for their CVD-grown  $\text{BiFeO}_3$  films ( $P_r \sim 0.2 \mu\text{C cm}^{-2}$ ,  $P_s \sim 1.75 \mu\text{C cm}^{-2}$ ) but lower than that reported for AACVD-grown  $\text{BiFeO}_3$  ( $8.7 \mu\text{C cm}^{-2}$ ).<sup>13</sup> However, given the shape of the loop and the associated large dielectric loss, the polarisation at zero electric field from these loops cannot be accurately ascribed to the electrical remnant polarisation. Magnetism measurements were performed on a  $\text{BiFeO}_3$  film deposited at  $550^\circ\text{C}$  on glass at both 5 K and 300 K (Fig. 6, Inset). At 5 K, the film displayed weak ferromagnetic behavior, with a saturation magnetization of  $17.5 \text{ emu cm}^{-3}$ , slightly larger than that expected for  $\text{BiFeO}_3$  from DFT calculations.<sup>18,45</sup> At 300 K, the saturation magnetisation decreased to  $4.9 \text{ emu cm}^{-3}$ , more consistent with the expected value for  $\text{BiFeO}_3$ .<sup>46,47</sup> and a decrease in coercivity ( $\sim 80 \text{ Oe}$ ) was also observed. For clarity, enlarged plots of the magnetic coercivity at both temperatures may be found in the ESI, Fig. S8 and S9.† The temperature dependence of the magnetisation (field cooled (FC) and zero field cooled (ZFC) curves under a 200 Oe applied field is shown in Fig. 6.

The sharp cusp at  $\sim 48 \text{ K}$  in the ZFC data has been observed previously and is characteristic of spin-glass behaviour ( $T_B$ , blocking temperature).<sup>48–50</sup> Above 50 K, the ZFC data reveals an increase in magnetisation due to spin re-alignment, however at elevated temperatures thermal motion predominates and the spins randomly orientate themselves resulting in a decrease in magnetisation, leading to a disordered state with no net magnetisation. Our findings are in agreement with those recorded by Scott *et al.*<sup>51</sup> for  $\text{BiFeO}_3$  single crystals – the splitting of the curves below 250 K is characteristic of spin-glass behaviour. The spins orientate themselves in a preferred direction, however if given sufficient thermal excitation can flip direction. If the measurement time of the magnetometer ( $\tau_M$ ) is smaller than the time taken for the spins to change

direction (Neel relaxation time  $\tau_N$ ) the magnetisation will not change during the measurement and the particle can be viewed in a “blocked” state unless the temperature is increased. It is important to establish what type of magnetism is present and hence we demonstrate that CVD-grown  $\text{BiFeO}_3$  films still possess good ferroelectric and ferromagnetic ordering and display spin-glass behaviour at low temperature.

The UV-vis absorption spectra of  $\text{BiFeO}_3$  films deposited at  $525^\circ\text{C}$  and  $550^\circ\text{C}$  at (8 mbar) are shown in Fig. 7(a). The band-gap ( $E_g$ ) of a semiconductor could be inferred from its UV-Vis spectra using the following equation:

$$(ah\nu)^n = A(h\nu - E_g)$$

where  $\alpha$  corresponds to the absorption coefficient,  $h\nu$  is the photon energy, and  $n$  represents the index which depends on the electronic transition of the semiconductor (for direct band-gap semiconductors,  $n = 2$ ).<sup>52</sup> In addition,  $A$  is a proportionality constant related to the material. The band-gap energy was obtained from the intercept of the tangent line in the plot of  $(ah\nu)^2$  versus energy (inset Fig. 7), and the value was determined to be between 2.3–2.5 eV for  $\text{BiFeO}_3$  for both samples in good agreement with literature reports.<sup>53,54</sup> A band-gap value of 2.18 eV was recently elucidated for  $\text{BiFeO}_3$  nanoparticles<sup>7</sup> and values of between 2.2–2.76 eV were found for thin films of  $\text{BiFeO}_3$  grown *via* sputtering; values in the higher part of this range were attributed to band-gap defect states and oxygen vacancies.<sup>55</sup> In our case the presence of additional  $\text{Bi}_{25}\text{FeO}_{40}$  phase at  $525^\circ\text{C}$  is likely to have an effect on the band-gap energy estimated, leading to an overall decrease compared to pure  $\text{BiFeO}_3$  which is in agreement with literature reports for  $\text{Bi}_{25}\text{FeO}_{40}$ .<sup>56</sup>

The photocurrent-voltage ( $I$ - $V$ ) and current-time ( $I$ - $T$ ) curves for a  $\text{BiFeO}_3$  film deposited directly onto a FTO-coated glass substrate at  $550^\circ\text{C}$  and illuminated using full arc AM 1.5 G and visible light ( $\lambda > 420 \text{ nm}$ ) are displayed in Fig. 7(b). As previously demonstrated,<sup>13</sup> we observe that the onset potential for  $\text{BiFeO}_3$  is 0.1 V (*vs.* Ag/AgCl), corresponding to a potential of  $\sim 0.6 \text{ V}$  *vs.* RHE. This is similar to the measured onset potential of  $\alpha\text{-Fe}_2\text{O}_3$  (haematite) electrodes, as expected given that both  $\text{BiFeO}_3$  and  $\alpha\text{-Fe}_2\text{O}_3$  possess similar flat-band potentials.<sup>57</sup> It also suggests that because the onset potential is considerably more positive than the flat-band potential (by approximately 0.3 V for  $\text{BiFeO}_3$ ), there are a number of serious limiting factors governing the photocurrent produced by  $\text{BiFeO}_3$  (*ca.*  $170 \mu\text{A cm}^{-2}$  at 1 V *vs.* Ag/AgCl), the reasons of which are likely to be similar to  $\alpha\text{-Fe}_2\text{O}_3$ .<sup>58</sup> The photocurrent generated under visible light is much lower, (*ca.*  $60 \mu\text{A cm}^{-2}$  at 1 V *vs.* Ag/AgCl); this shows that the majority (*ca.* 60%) of photocurrent generated by BFO is due to the small UV portion of the AM 1.5 G spectrum. Importantly, the onset potential under visible irradiation also shifts positively, suggesting that the majority of photocurrent produced by  $\text{BiFeO}_3$  is driven by higher energy UV photons. This is rationalised by the sharp increase in the absorption spectra below 400 nm (Fig. 7a); a similar phenomenon has recently been observed more

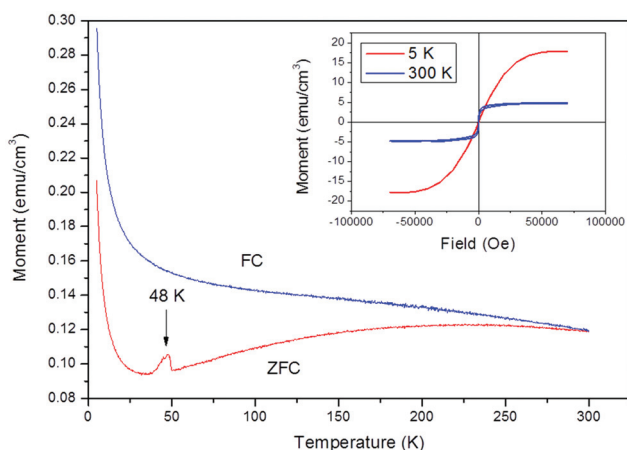
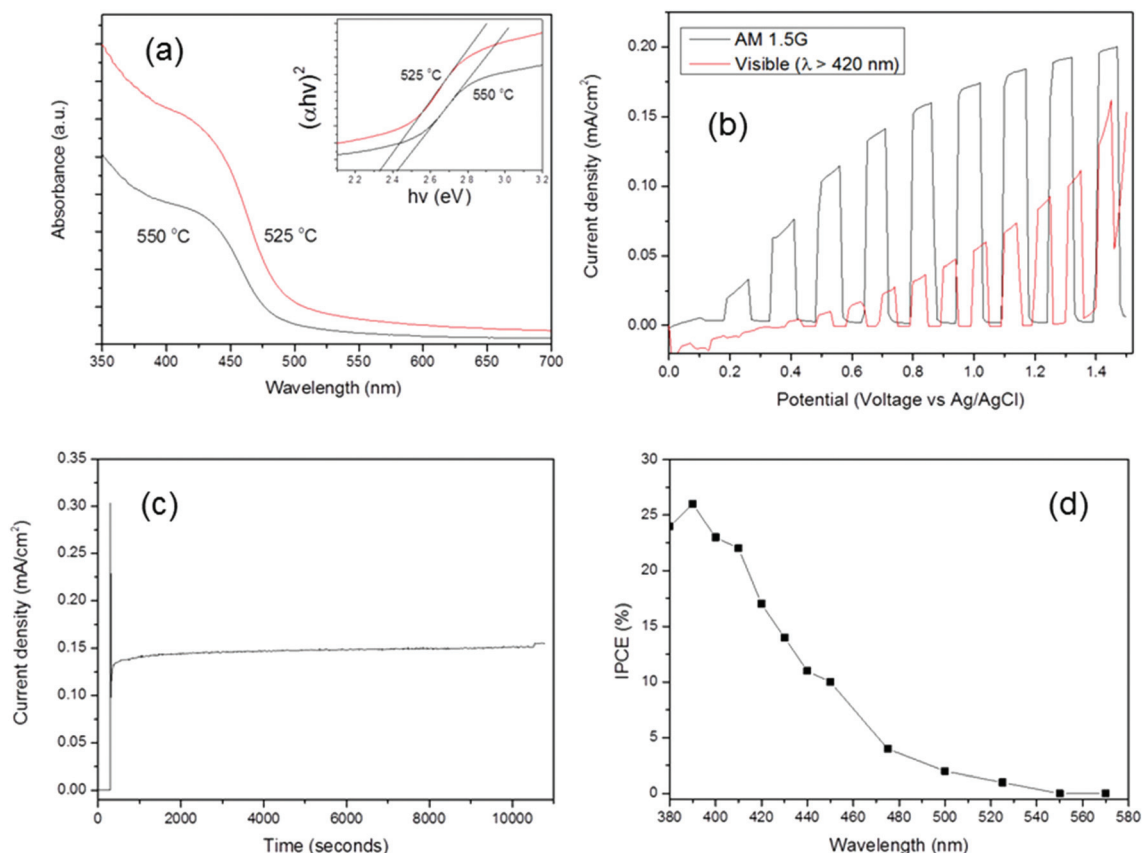


Fig. 6 ZFC and FC curves for the 880 nm thick  $\text{BiFeO}_3$  film formed *via* LPCVD at an applied field of 200 Oe.







**Fig. 7** (a) UV-vis absorption spectra of BiFeO<sub>3</sub> films grown at 525 and 550 °C via LPCVD. Inset figure shows the plot of  $(\alpha h\nu)^2$  versus energy for band-gap calculations; (b) *I*–*V* curve for BiFeO<sub>3</sub> under both 100 mW cm<sup>−2</sup> AM 1.5 G and visible light irradiation in Na<sub>2</sub>SO<sub>4</sub> electrolyte (pH 6.5); (c) *I*–*T* curve for BiFeO<sub>3</sub> measured under full arc AM 1.5 G illumination, at an applied potential of 1 V (vs. Ag/AgCl) for 3 hours; (d) IPCE spectrum for BiFeO<sub>3</sub> photoelectrode measured at 1.2 V (vs. RHE).

dramatically on Au/BiFeO<sub>3</sub>, where under UV-Vis excitation a near fivefold increase in oxygen evolution was measured compared to that under visible irradiation ( $\lambda > 420$  nm).<sup>59</sup> A similar increase in absorption below 400 nm was observed. This is significant particularly in the case of BiFeO<sub>3</sub>, which is widely reported to be a visible-light driven photocatalyst, and currently we are investigating the reasons behind these phenomena. Nevertheless, this clearly demonstrates visible-light driven activity for BiFeO<sub>3</sub> photoanodes. It is also higher than that reported recently for epitaxial BFO/SRO/STO films grown by RF sputtering.<sup>60</sup> Strikingly, the transient photocurrent, recorded at 1 V vs. Ag/AgCl for a period of three hours under full arc irradiation (Fig. 7c), revealed very good stability for BiFeO<sub>3</sub>, with no obvious loss of activity during the test. In order to assess the light harvesting efficiency of the BiFeO<sub>3</sub> photoelectrode, IPCE (Fig. 7d)) was measured using a monochromator under an applied voltage of 1.2 V vs. RHE (0.6 V vs. Ag/AgCl). The IPCE at 420 nm was recorded as 17%, a marked improvement over the *ca.* 4% recorded at a similar voltage (0.5 V vs. Ag/AgCl) by Chen *et al.*<sup>61</sup> for PLD-grown BiFeO<sub>3</sub> electrodes and is in good agreement with the band-gap absorption edge of approximately 480 nm exhibited in the UV-vis absorption spectra (Fig. 7a)). This demonstrates that these CVD-grown

BiFeO<sub>3</sub> films possess superior light harvesting and charge transfer characteristics and compare favourably to those recorded for spray-deposited mesoscopic  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> electrodes.<sup>62</sup> There are a variety of reasons for the observed enhancement in PEC behaviour. The LPCVD process is able to deposit phase-pure, highly conformal, nanostructured films in comparison to other methods of film deposition, thus enabling a high surface area and more reaction sites. This is evidenced by the higher photocurrent exhibited for these LPCVD-grown BiFeO<sub>3</sub> films compared to films grown *via* AACVD, which exhibited no obvious well-defined nanostructuring.<sup>13</sup> Furthermore, ferroelectric measurements confirmed room temperature polarisation in these films; the internal dipolar field within a ferroelectric creates charged surfaces that cause photogenerated carriers to move in opposite directions, which separates electrons and holes and causes oxidation and reduction products to be generated at different locations.<sup>14</sup> This has already been demonstrated in BiFeO<sub>3</sub> photocatalysts and is akin to an internal *p*–*n* junction.<sup>63,64</sup>

In order to verify that BiFeO<sub>3</sub> can produce oxygen from photocatalytic water splitting under visible light, films deposited at 525 °C and 550 °C at (8 mbar) were investigated for photo-oxidation of water using persulphate ions as a sacrificial

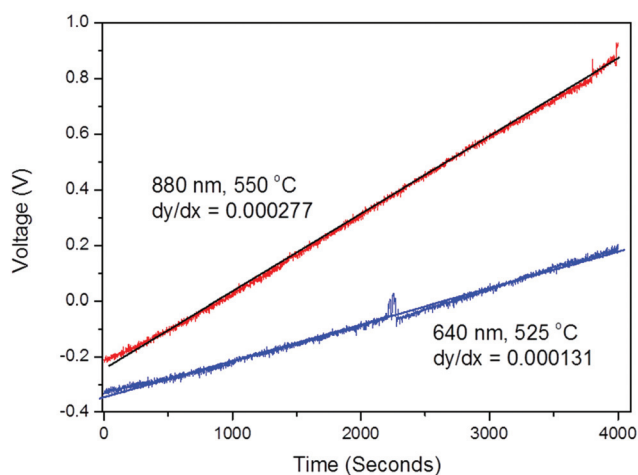


electron scavenger under simulated visible light irradiation ( $\lambda > 420$  nm) in the absence of external bias and co-catalysts (see Experimental section).<sup>65</sup> An oxygen electrode (Clark cell) was used to measure the voltage as a function of time, which is proportional to the dissolved oxygen concentration in the solution, and when an uncoated substrate was tested, no oxygen evolution was detected as expected. The Clark cell is extremely accurate for immediately detecting low concentrations of oxygen dissolved in aqueous electrolytes. Each film was suspended in the solution and irradiated with the light source for approximately 70 minutes and graphs plotting voltage against time for the two samples are shown in Fig. 8. Both films displayed appreciable photo-activities over the duration of the experiment. The small spike in the data recorded for the 640 nm thick film is due to the very high sensitivity of the oxygen electrode resulting in the detection of a brief, sharp increase in voltage; however this does not affect the overall gradient of the slope. As a control experiment, no increase in voltage was detected under dark conditions or in the absence of photocatalyst.

The rate of oxygen production observed under visible irradiation (Table 2) were 1–2 orders of magnitude higher than those obtained from the use of anatase films deposited on glass *via* APCVD ( $360\text{--}2820\ \mu\text{mol h}^{-1}\text{ m}^{-2}$ ) using a 365 nm UV-light source,<sup>66</sup> and are higher than those recently reported for

BiFeO<sub>3</sub> grown *via* AACVD.<sup>13</sup> Joshi *et al.* have investigated the potential of BiFeO<sub>3</sub> nanocubes to serve as visible-light water oxidation catalysts and found low activities in the region of  $2.5\ \mu\text{mol O}_2$  after 12 hours, at a rate of  $0.5\ \mu\text{mol h}^{-1}$ .<sup>67</sup> However, very high surface area mesoporous BiFeO<sub>3</sub> was recently reported to exhibit an oxygen evolution rate of *ca.*  $66\ \mu\text{mol g}^{-1}\text{ h}^{-1}$ .<sup>59</sup> Clearly, quantum yield is not the optimal method to measure the efficiency of thin film photoelectrodes; thus we place emphasis of Faradaic efficiency and IPCE (see later). However, on a per gram basis, taking the density of BiFeO<sub>3</sub> to be  $\sim 9\ \text{g cm}^{-3}$  with the film volume of *ca.*  $6 \times 10^{-10}\ \text{m}^3$ , the actual mass of BiFeO<sub>3</sub> present would be  $\sim 6\ \text{mg}$ .<sup>68</sup> On a per gram basis, the oxygen evolution would be between  $250\text{--}520\ \mu\text{mol h}^{-1}\text{ g}^{-1}$ , much higher than the recently aforementioned mesoporous BiFeO<sub>3</sub>. There are several reasons why the photocatalytic activity is comparable to, or much higher than those previously observed for BiFeO<sub>3</sub>. Firstly, our films possess a high surface area as demonstrated by the relatively high roughness values found using AFM analysis. Secondly, the likelihood of introducing charge trapping sites from parasitic phases is much lower due to the high purity of the films deposited at  $550\ ^\circ\text{C}$  in our system, as evidenced in the lower performance of the film deposited at  $525\ ^\circ\text{C}$ . In agreement with the transient photocurrent test, there were no distinct changes observed *via* XRD for both samples after being submerged in the basic electrolyte and irradiated with the solar simulator, thus demonstrating excellent stability for BiFeO<sub>3</sub> photocatalysts grown *via* this CVD method.

In order to improve the kinetics for the sluggish process of water oxidation on BiFeO<sub>3</sub>, a Nickel borate (Ni-B) oxygen evolution catalyst (OEC) was introduced *via* photo-assisted electro-deposition to the BiFeO<sub>3</sub> grown on FTO glass.<sup>69,70</sup> The OEC catalyst functions through collection of photoholes from the light absorbing semiconductor, thus aiding charge separation, and also lowers the activation energy for water oxidation, which occurs solely on its surface. The mechanism of its formation has recently been explained by Park *et al.* for their BiVO<sub>4</sub> photoanodes.<sup>70</sup> In addition, we recently demonstrated that the Ni-B OEC possesses further functionality as an inert, earth abundant passivation layer for unstable photoelectrodes.<sup>71</sup> The high resolution XPS spectrum of the Ni 2p region is shown in the ESI Fig. S10,† revealing the presence of nickel in the OEC as Ni<sup>2+</sup>. The *I*-*V* curve of a Ni-B/BiFeO<sub>3</sub> photoelectrode under full arc conditions tested in aqueous 0.1 M potassium borate electrolyte is shown in Fig. 9a. The photocurrent reaches a maximum of  $0.72\ \text{mA cm}^{-2}$  at 1 V *vs.* Ag/AgCl, which is over four times higher than that exhibited by the bare BiFeO<sub>3</sub> electrode (Fig. 7b). Furthermore, the onset potential has cathodically shifted by almost 0.3 V, similar to our recent result with ZnO photoanodes,<sup>71</sup> and shows that the OEC efficiently traps photoholes on the surface for the oxygen evolution reaction. This is crucial for widening the operating window of a PEC device in order to operate under minimum external bias. The increase in dark current above 1 V (*vs.* Ag/AgCl) is likely due to the electrocatalytic function of the OEC or due to the Ni<sup>2+</sup>/Ni<sup>3+</sup> redox peak.<sup>70</sup> The stability of the junc-



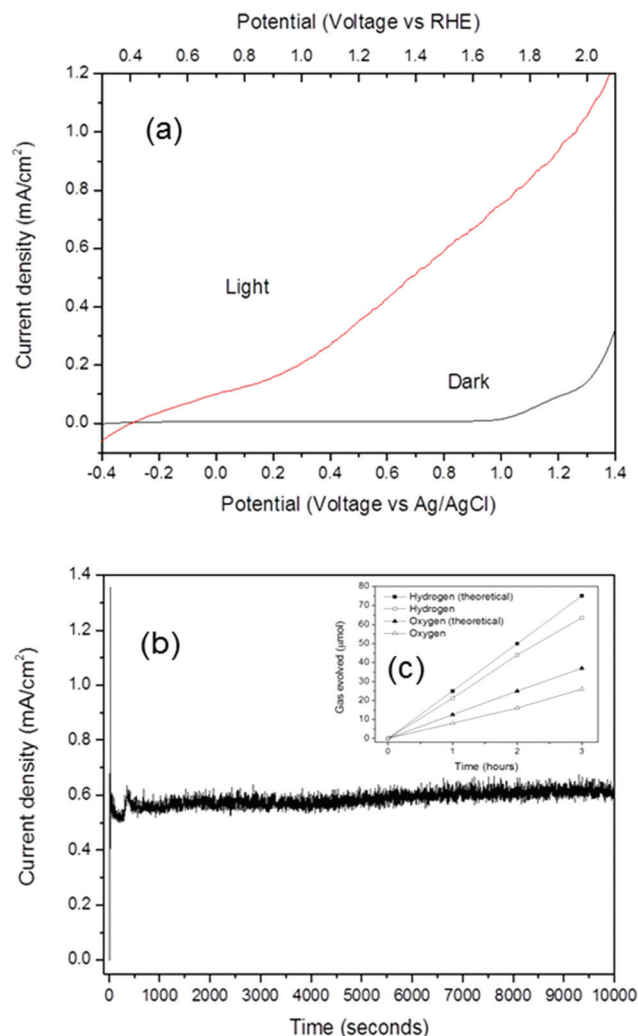
**Fig. 8** Plots of voltage against time measured during the photo-oxidation of water (without applied bias) for two BiFeO<sub>3</sub> films of 880 nm and 640 nm thicknesses under visible light illumination ( $\lambda > 420$  nm). The gradient of the slope was used to calculate the rate of oxygen produced.

**Table 2** Summary of the individual film properties and the rate of oxygen production for the two films chosen

Phase(s) obtained	Film thickness/nm	Band-gap/eV	Rate of O <sub>2</sub> production/ $\mu\text{mol h}^{-1}$	Rate of O <sub>2</sub> production/ $\mu\text{mol h}^{-1}\text{ m}^{-2}$
BiFeO <sub>3</sub> + Bi <sub>25</sub> FeO <sub>40</sub>	640	2.3	1.49	7400
BiFeO <sub>3</sub>	880	2.4	3.14	15 700







**Fig. 9** (a) *I*–*V* curve for a Ni–B/BiFeO<sub>3</sub> photoanode under 100 mW cm<sup>−2</sup> AM 1.5 G irradiation in 0.1 M potassium borate electrolyte (pH 9.2); (b) corresponding transient photocurrent for Ni–B/BiFeO<sub>3</sub> measured at an applied potential of 1 V (vs. Ag/AgCl) for 3 hours; (c) inset figure shows PEC gas evolution over Ni–B/BiFeO<sub>3</sub> photoelectrode compared with the theoretical gas evolution deduced from photocurrent generation.

tion photoelectrode was confirmed through prolonged testing (almost 3 hours) with no loss of current detected (Fig. 9b), thus confirming the Ni–B/BiFeO<sub>3</sub> junction is stable under the operating conditions. Importantly, Faradaic efficiency was determined to provide further verification of the water splitting reaction on Ni–B/BiFeO<sub>3</sub> photoanodes. As can be seen from Fig. 9c, stoichiometric gas evolution, close to 70% Faradaic efficiency is observed for oxygen and over 85% for hydrogen evolution over a 3 hour test period, demonstrating that BiFeO<sub>3</sub> could serve as an alternative, stable photoanode material for water splitting reactions because most of the photogenerated charges were consumed for water splitting and H<sub>2</sub>/O<sub>2</sub> production in the current system. It is worth mentioning that O<sub>2</sub> dissolved in the electrolyte is not measured by the GC which can result in an underestimation of Faradaic efficiency. Moreover, the lack of

separation between evolved gases in the single compartment PEC cell and systematic error in gas measurement using gas syringe and GC (which are not contained together within a closed system) yields efficiencies that can deviate from unity. In spite of these limitations, these results clearly demonstrate the potential of BiFeO<sub>3</sub> thin films to act as powerful visible-light photocatalysts for the kinetically slow four electron process of water oxidation and could be promising photocatalysts for environmental remediation applications.

## Conclusions

For the first time, we demonstrate the growth of high quality, pure phase multiferroic BiFeO<sub>3</sub> films *via* dual-source LPCVD using the ligand-matched solid organometallic precursors [Fe(O<sup>*i*</sup>Bu)<sub>3</sub>]<sub>2</sub> and [Bi(O<sup>*i*</sup>Bu)<sub>3</sub>] without the need for an additional oxygen source. The effect on the phase(s) of BFO obtained whilst varying the CVD system pressure and growth temperature was investigated, and it was found that a temperature of 550 °C was required to obtain phase-pure BiFeO<sub>3</sub>, and that an increase in system pressure brought about a variation in morphology to crescent-shaped nanoparticulate clusters. Films displayed ferromagnetic magnetisation and spin-glass behaviour, together with weak ferroelectric polarisation due to the absence of epitaxial strain caused by lattice mismatch, thus confirming multiferroic properties at room temperature. The photocatalytic activity of the films was assessed *via* PEC measurements and water oxidation using persulfate ions as an electron scavenger, which revealed very high activity for these BFO films. The initial enhanced activity was ascribed to the high surface area, nanostructured morphology brought about by the LPCVD process, coupled with an improved charge separation efficiency induced by the internal polarisation present within perovskite BiFeO<sub>3</sub>. For the first time we observe a visible light driven PEC response from BiFeO<sub>3</sub> in the absence of any scavengers with concomitant hydrogen and oxygen gas evolution, which is promising not only for photocatalytic water splitting but also for environmental remediation applications. In addition, we have shown that a surface Ni OEC can enhance the oxygen production on BiFeO<sub>3</sub>, by improving the reaction kinetics and lowering the overpotential for water oxidation. Further enhancement could be possible with the incorporation of noble metal particles to improve charge separation or through doping.<sup>30</sup> Furthermore our results complement those recently reported for Au-BFO nanowires which recently exhibited a dramatic oxygen evolution rate under visible light irradiation and demonstrate the potential of BiFeO<sub>3</sub> as a viable replacement for hematite photoanodes once further studies concerning carrier dynamics are undertaken.<sup>12</sup>

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[Fe(O<sup>t</sup>Bu)<sub>3</sub>]<sub>2</sub>. SM and JT acknowledge financial support from the EU FP7 Project 4G-PHOTO CAT – 309636.

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